



PUMD3-Q

50 V, 100 mA NPN/PNP resistor-equipped double transistor;
R1 = 10 k Ω , R2 = 10 k Ω

7 October 2021

Product data sheet

1. General description

NPN/PNP Resistor-Equipped double Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PUMH11-Q

PNP/PNP complement: PUMB11-Q

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Digital application in automotive and industrial segments
- Cost-saving alternative for BC847-Q/BC857-Q series in digital applications
- Controlling IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

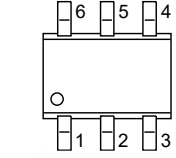
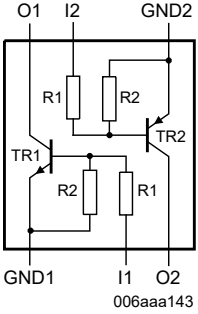
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|---------------------------|------------|-----|-----|-----|------------|
| Per transistor, for the PNP transistor with negative polarity | | | | | | |
| V _{CEO} | collector-emitter voltage | open base | - | - | 50 | V |
| I _o | output current | | - | - | 100 | mA |
| R1 | bias resistor 1 | [1] | 7 | 10 | 13 | k Ω |
| R2/R1 | bias resistor ratio | [1] | 0.8 | 1 | 1.2 | |

[1] See "Section 11: Test information" for resistor calculation and test conditions.

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|------------------------|--|---|
| 1 | GND1 | GND (emitter) TR1 |  <p>TSSOP6 (SOT363)</p> |  |
| 2 | I1 | input (base) TR1 | | |
| 3 | O2 | output (collector) TR2 | | |
| 4 | GND2 | GND (emitter) TR2 | | |
| 5 | I2 | input (base) TR2 | | |
| 6 | O1 | output (collector) TR1 | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|---|---------|
| | Name | Description | Version |
| PUMD3-Q | TSSOP6 | plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body | SOT363 |

7. Marking

Table 4. Marking codes

| Type number | Marking code[1] |
|-------------|-----------------|
| PUMD3-Q | D%3 |

[1] % = placeholder for manufacturing site code

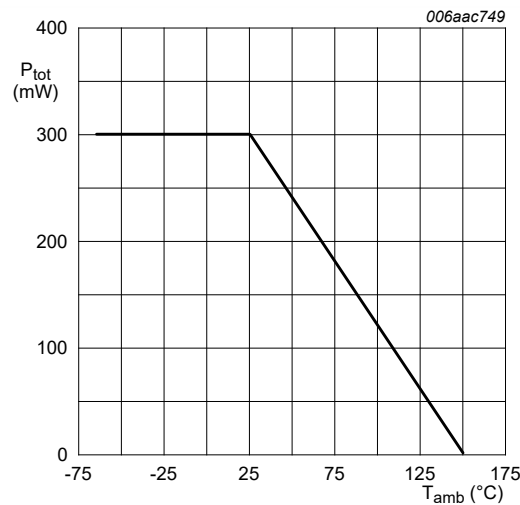
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|--|---------------------------|--------------------------|-----|-----|-----|------|
| Per transistor, for the PNP transistor with negative polarity | | | | | | |
| V _{CBO} | collector-base voltage | open emitter | | - | 50 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | 50 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | 10 | V |
| V _I | input voltage | input voltage TR1 | | - | 40 | V |
| | | | | - | -10 | V |
| | | input voltage TR2 | | - | 10 | V |
| | | | | - | -40 | V |
| I _O | output current | | - | 100 | mA | |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 200 | mW |
| Per device | | | | | | |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 300 | mW |
| T _j | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -65 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 μm copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint

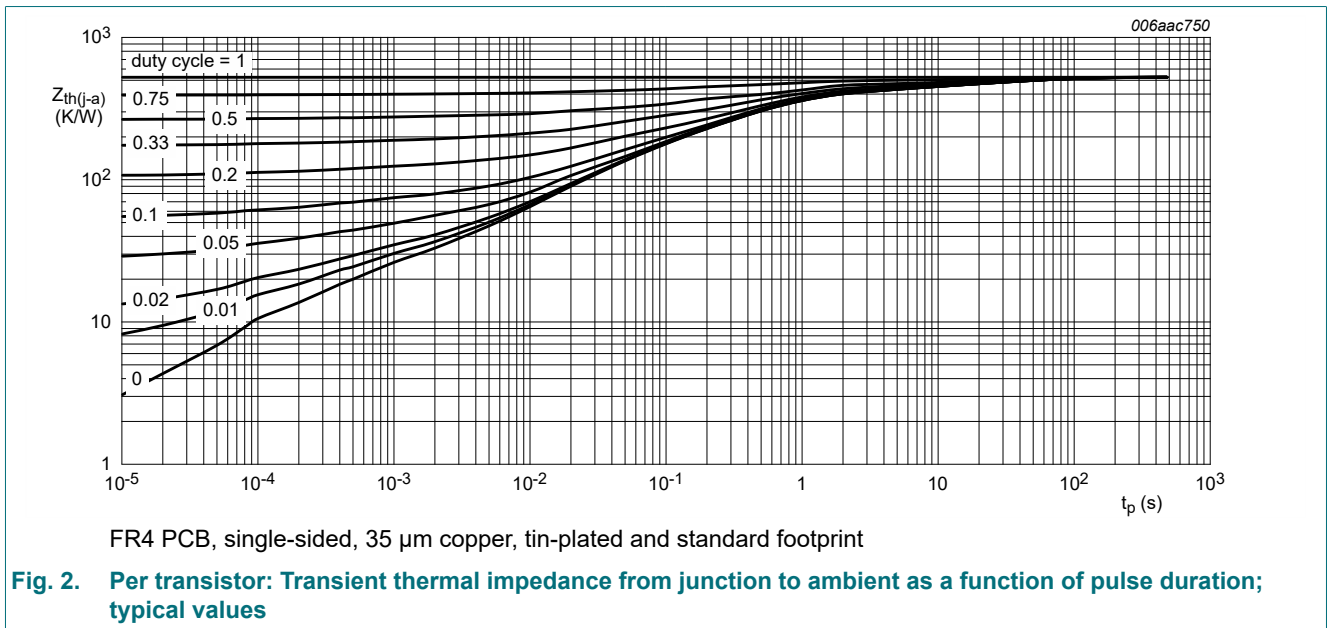
Fig. 1. Per device: Power derating curve

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|-----------------------|---|-------------|-----|-----|-----|-----|------|
| Per transistor | | | | | | | |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] | - | - | 625 | K/W |
| Per device | | | | | | | |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1] | - | - | 417 | K/W |

[1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.



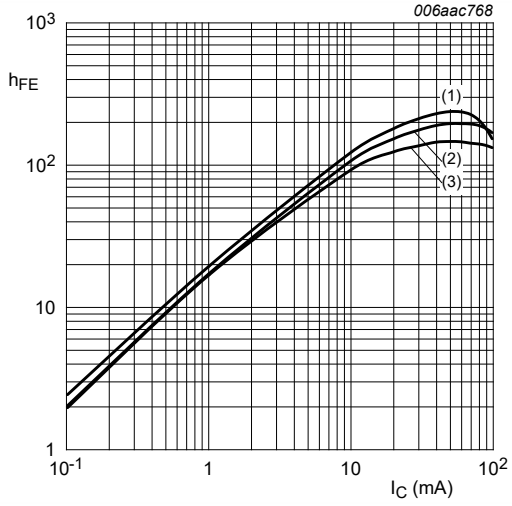
10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--|--------------------------------------|---|-----|-----|-----|---------------|----|
| Per transistor, for the PNP transistor with negative polarity | | | | | | | |
| $V_{(BR)CBO}$ | collector-base breakdown voltage | $I_C = 100 \mu\text{A}; I_E = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | 50 | - | - | V | |
| $V_{(BR)CEO}$ | collector-emitter breakdown voltage | $I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | 50 | - | - | V | |
| I_{CBO} | collector-base cut-off current | $V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | - | - | 100 | nA | |
| I_{CEO} | collector-emitter cut-off current | $V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | - | - | 100 | nA | |
| | | $V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}; T_j = 150 \text{ }^\circ\text{C}$ | - | - | 5 | μA | |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = 5 \text{ V}; I_C = 0 \text{ mA}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | - | - | 400 | μA | |
| h_{FE} | DC current gain | $V_{CE} = 5 \text{ V}; I_C = 5 \text{ mA}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | 30 | - | - | | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | - | - | 100 | mV | |
| $V_{I(off)}$ | off-state input voltage | $V_{CE} = 5 \text{ V}; I_C = 100 \mu\text{A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | - | 1.1 | 0.8 | V | |
| $V_{I(on)}$ | on-state input voltage | $V_{CE} = 0.3 \text{ V}; I_C = 10 \text{ mA}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | 2.5 | 1.8 | - | V | |
| R1 | bias resistor 1 | | [1] | 7 | 10 | 13 | kΩ |
| R2/R1 | bias resistor ratio | | [1] | 0.8 | 1 | 1.2 | |
| TR1 (NPN) | | | | | | | |
| C_c | collector capacitance | $V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | - | - | 2.5 | pF | |
| f_T | transition frequency | $V_{CE} = 5 \text{ V}; I_C = 10 \text{ mA}; f = 100 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | [2] | 230 | - | MHz | |
| TR2 (PNP) | | | | | | | |
| C_c | collector capacitance | $V_{CB} = -10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | - | - | 3 | pF | |
| f_T | transition frequency | $V_{CE} = -5 \text{ V}; I_C = -10 \text{ mA}; f = 100 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ | [2] | 180 | - | MHz | |

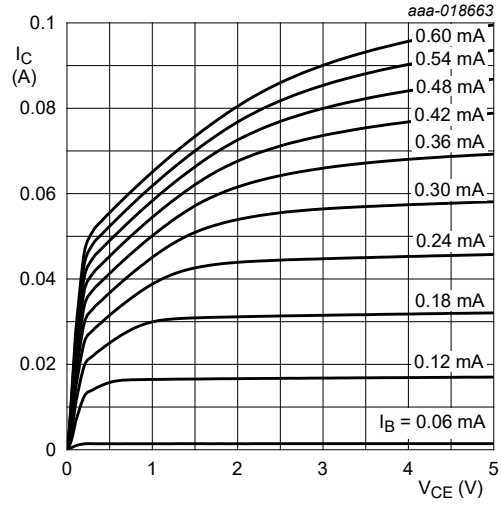
[1] See "Section 11: Test information" for resistor calculation and test conditions.

[2] Characteristics of built-in transistor



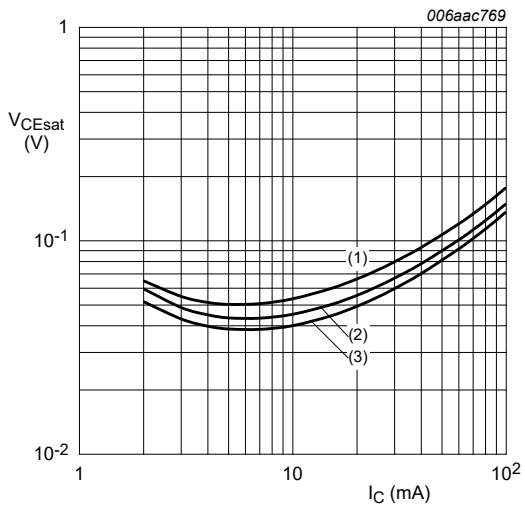
$V_{CE} = 5\text{ V}$
 (1) $T_{amb} = 100\text{ }^\circ\text{C}$
 (2) $T_{amb} = 25\text{ }^\circ\text{C}$
 (3) $T_{amb} = -40\text{ }^\circ\text{C}$

Fig. 3. TR1 (NPN): DC current gain as a function of collector current; typical values



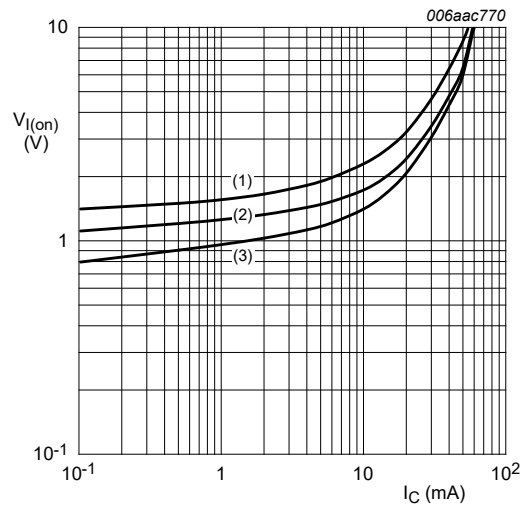
$T_{amb} = 25\text{ }^\circ\text{C}$

Fig. 4. TR1 (NPN): Collector current as a function of collector-emitter voltage; typical values



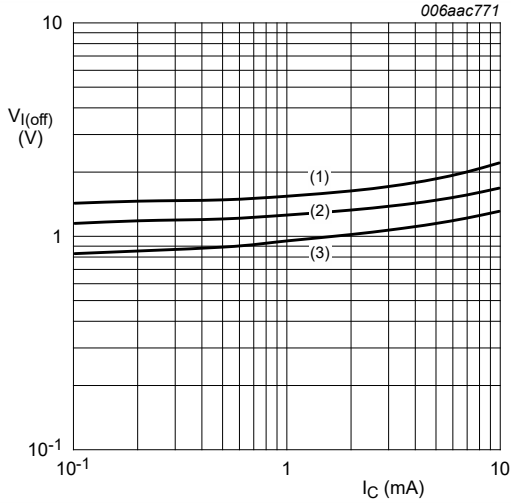
$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ }^\circ\text{C}$
 (2) $T_{amb} = 25\text{ }^\circ\text{C}$
 (3) $T_{amb} = -40\text{ }^\circ\text{C}$

Fig. 5. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



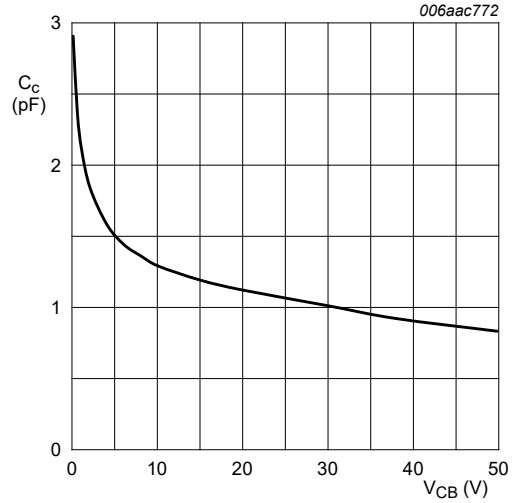
$V_{CE} = 0.3\text{ V}$
 (1) $T_{amb} = -40\text{ }^\circ\text{C}$
 (2) $T_{amb} = 25\text{ }^\circ\text{C}$
 (3) $T_{amb} = 100\text{ }^\circ\text{C}$

Fig. 6. TR1 (NPN): On-state input voltage as a function of collector current; typical values



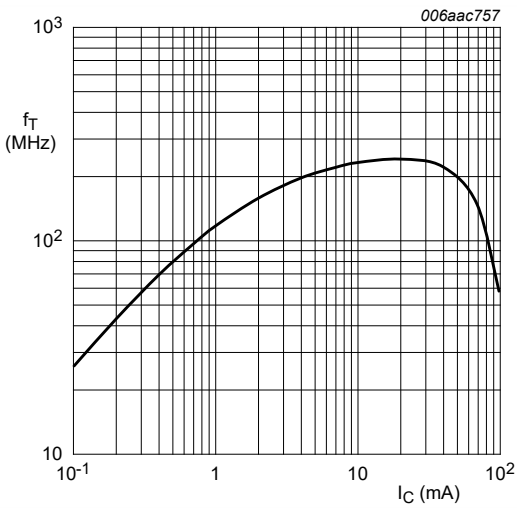
$V_{CE} = 5 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 7. TR1 (NPN): Off-state input voltage as a function of collector current; typical values



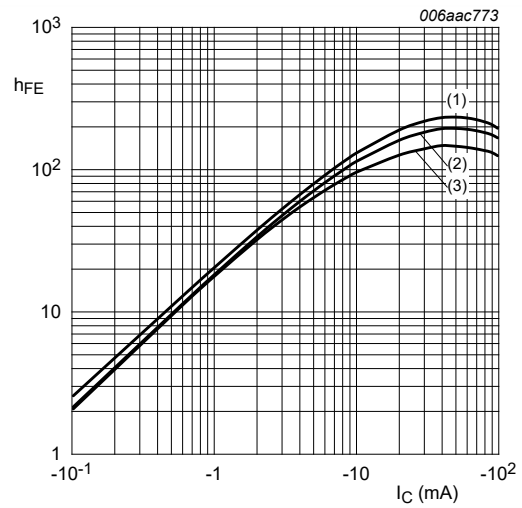
$f = 1 \text{ MHz}$
 $T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 8. TR1 (NPN): Collector capacitance as a function of collector-base voltage; typical values



$f = 100 \text{ MHz}$
 $T_{amb} = 25 \text{ }^\circ\text{C}$
 $V_{CE} = 5 \text{ V}$

Fig. 9. TR1 (NPN): Transition frequency as a function of collector current; typical values of built-in transistor



$V_{CE} = -5 \text{ V}$
 (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

Fig. 10. TR2 (PNP): DC current gain as a function of collector current; typical values

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 kΩ, R2 = 10 kΩ

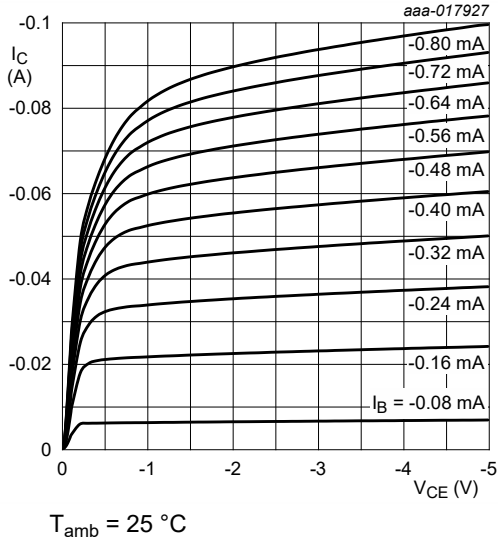


Fig. 11. TR2 (PNP): Collector current as a function of collector-emitter voltage; typical values

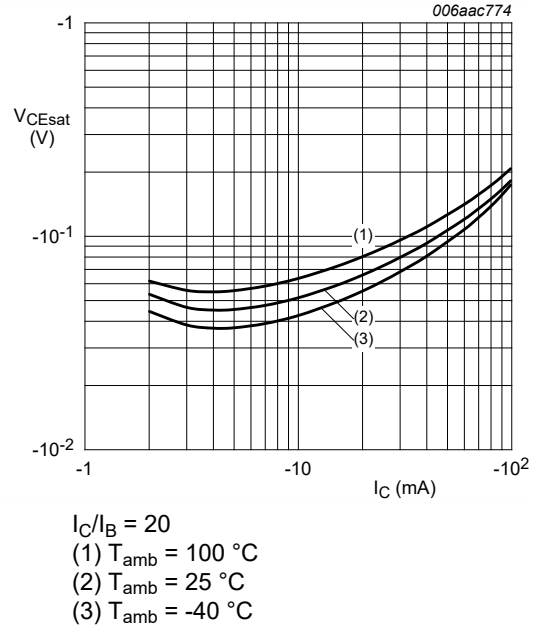


Fig. 12. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

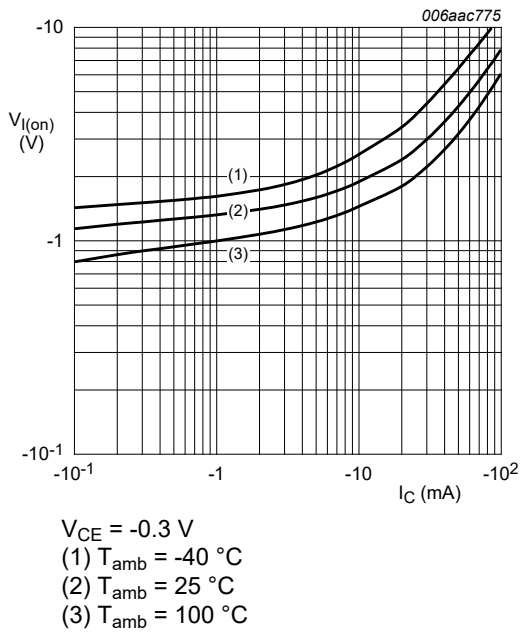


Fig. 13. TR2 (PNP): On-state input voltage as a function of collector current; typical values

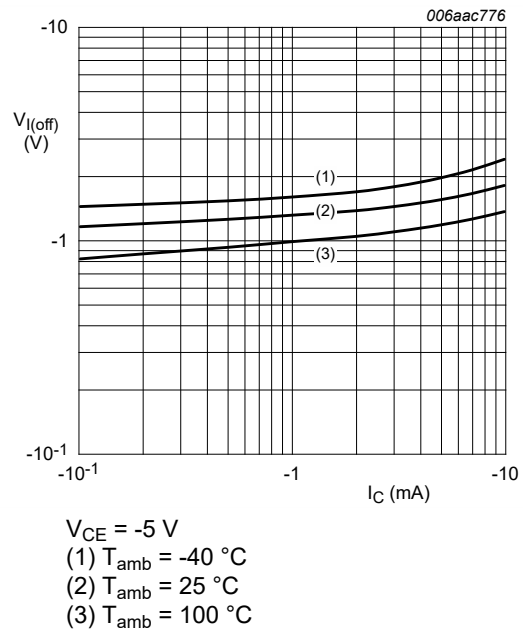
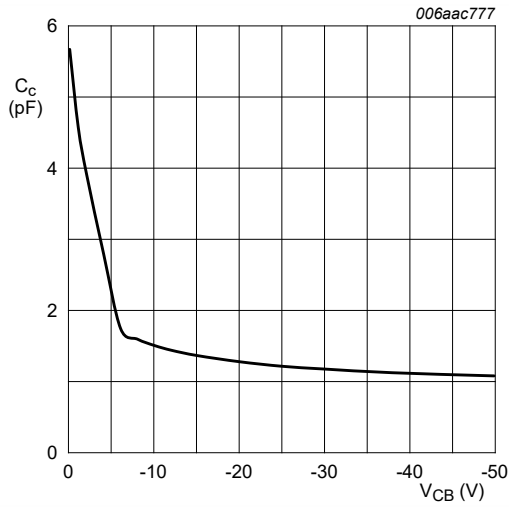
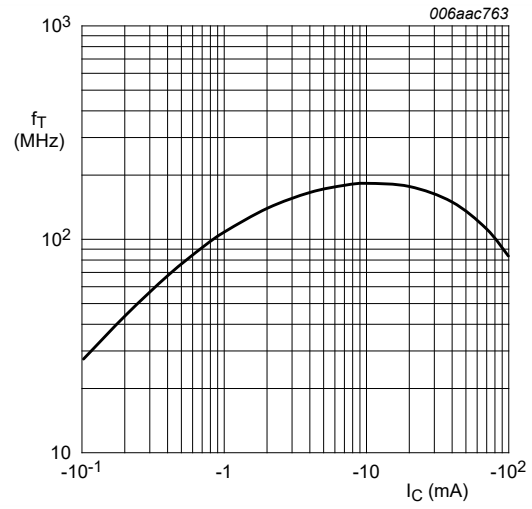


Fig. 14. TR2 (PNP): Off-state input voltage as a function of collector current; typical values



$f = 1 \text{ MHz}$
 $T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 15. TR2 (PNP): Collector capacitance as a function of collector-base voltage; typical values



$f = 100 \text{ MHz}$
 $T_{amb} = 25 \text{ }^\circ\text{C}$
 $V_{CE} = -5 \text{ V}$

Fig. 16. TR2 (PNP): Transition frequency as a function of collector current; typical values of built-in transistor

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I12) - V(I11)}{I12 - I11}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

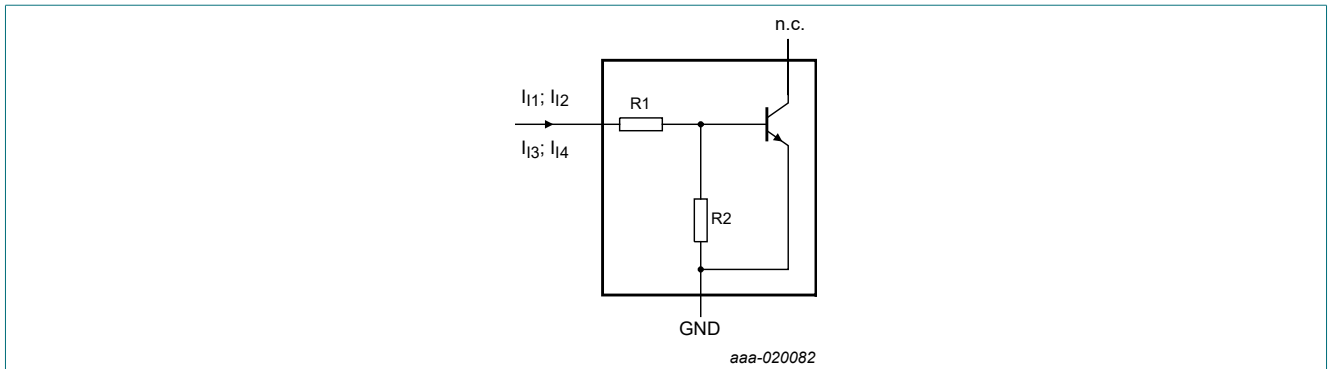


Fig. 17. TR1 (NPN): Resistor test circuit

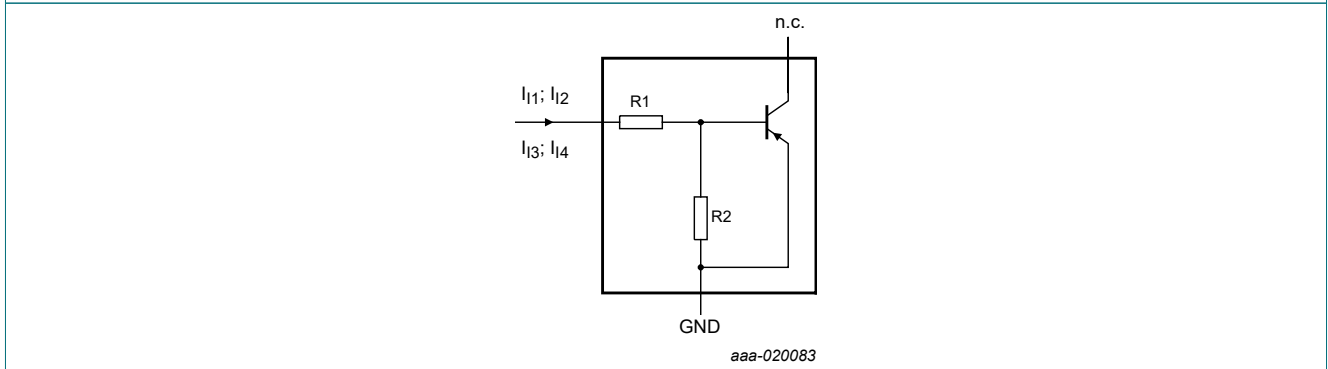


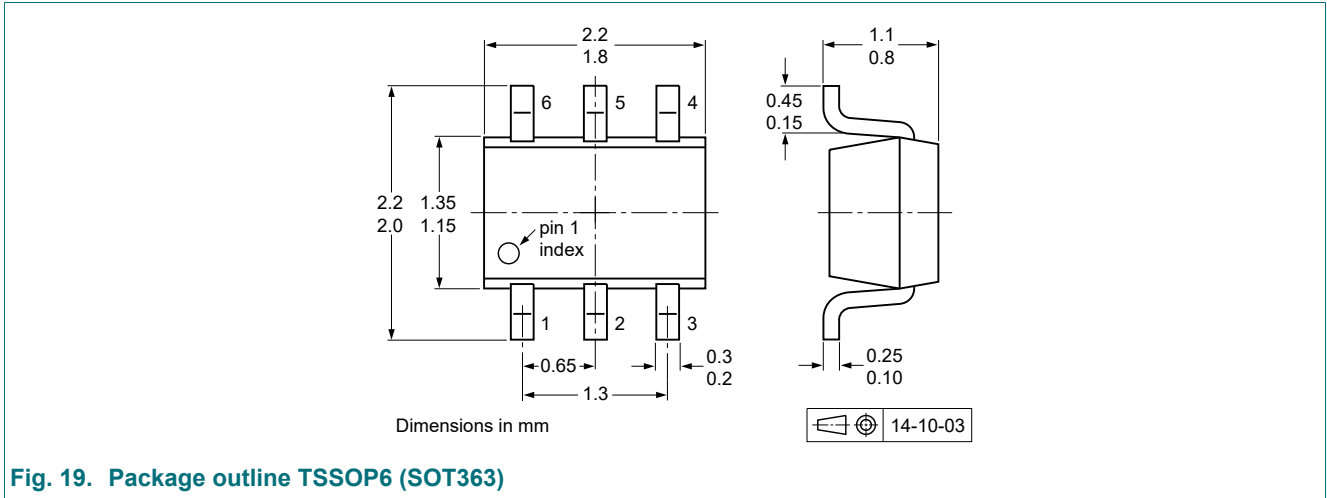
Fig. 18. TR2 (PNP): Resistor test circuit

Resistor test conditions

Table 8. Resistor test conditions

| Type number | R1 (kΩ) | R2 (kΩ) | Test conditions | | | |
|---|---------|---------|-----------------|--------|---------|---------|
| | | | I11 | I12 | I13 | I14 |
| Per transistor, for the PNP with negative polarity | | | | | | |
| PUMD3-Q | 10 | 10 | 350 μA | 450 μA | -350 μA | -450 μA |

12. Package outline



13. Soldering

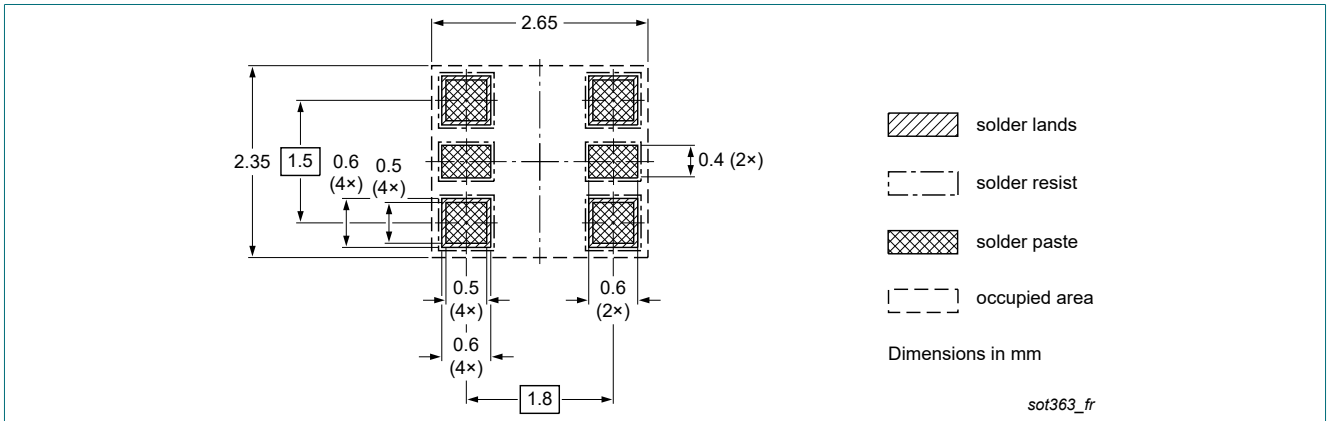


Fig. 20. Reflow soldering footprint for TSSOP6 (SOT363)

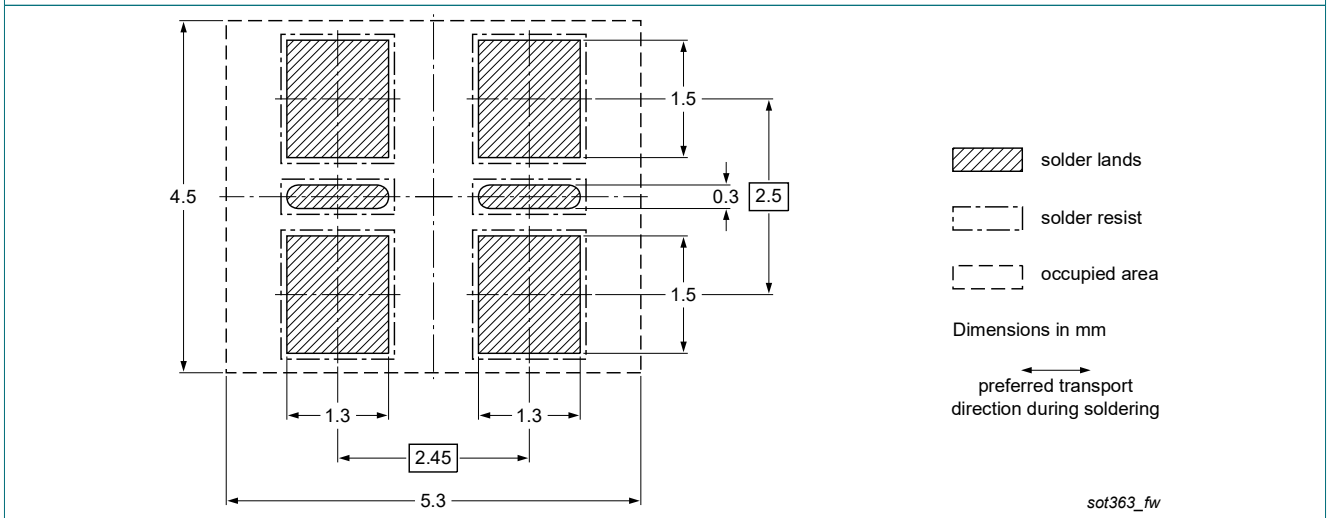


Fig. 21. Wave soldering footprint for TSSOP6 (SOT363)

14. Revision history

Table 9. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
|---------------|---|--------------------|---------------|-------------|
| PUMD3-Q v.2 | 20211007 | Product data sheet | - | PUMD3-Q v.1 |
| Modification: | <ul style="list-style-type: none"> • Complete rework • General description: added new lines at the end • Applications: Clarification updated • Pinning: Graphic symbol replaced • Limiting values: deleted parameter I_{CM} • Characteristics: I_{CEO} max limit is updated to 100 nA • Characteristics: V_{CEsat} limit is now updated to 100 mV • Characteristics: added new graphics • Characteristics: Updated the graphics conditions • Characteristics: $V_{(BR)EBO}$ values is removed • Test information: Included resistor calculation, resistor test circuit and resistor test condition | | | |
| PUMD3-Q v.1 | 20210624 | Product data sheet | - | - |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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